# NSN 5962-01-354-3863

Memory Microcircuit - Page 1 of 1



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# Body Length:

0.785 inches

## **Body Width:**

0.310 inches

# **Body Height:**

0.185 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

## **Features Provided:**

Hermetically sealed and burn in and bipolar and w/enable and programmed

## Inclosure Material:

Ceramic

### Inclosure Configuration:

Dual-in-line

## **Output Logic Form:**

Transistor-transistor logic

### Input Circuit Pattern:

10 input

## **Current Rating Per Characteristic:**

130.00 milliamperes reverse current, dc absolute

# **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

-0.5 volts power source and 7.0 volts power source

## Time Rating Per Chacteristic:

60.00 nanoseconds access

## Memory Device Type:

Prom

## **Test Data Document:**

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

## **Terminal Type And Quantity:**

16 printed circuit

#### Shelf Life:

N/a

# Unit Of Measure:

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## Demilitarization:

Yes - demil/mli

## Fiig:

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